/ Descriptions

TO-220F N 0V

N-CHANNEL 650V Super-Junction Power MOSFET in a TO-220F Plastic Package.

/ Features

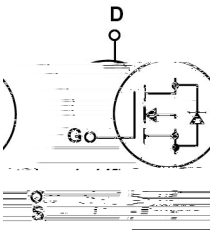
$R_{DS(on)}$×Qg 100% ROHS

Very low $R_{DS(on)}$×Qg,100% avalanche tested,RoHS compliant.

/ Applications

For switch mode power supply, uninterruptible power supply, power factor correction.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 D PIN 3 S

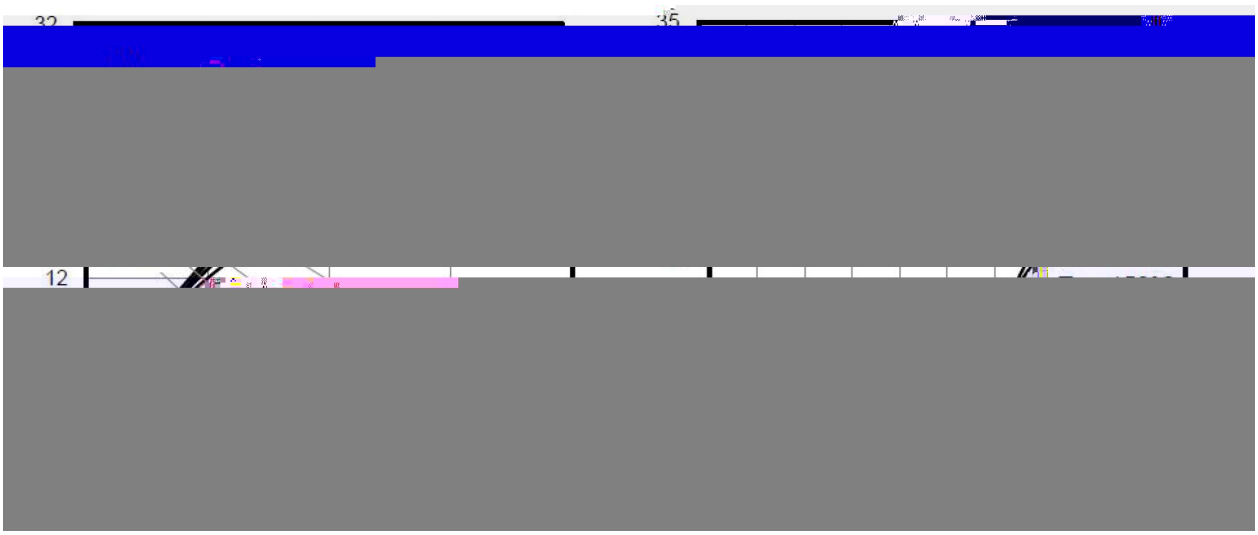
/ Marking

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	650	V
Drain Current	I_D(Tc=25)	11	A
Drain Current - Pulsed	I_{DM}	44	A
Gate-Source Voltage	V_{GS}	±30	V
Single Pulsed Avalanche Energy	E_{AS}	277	mJ
Avalanche Current	I_{AS}	8	A
Power Dissipation	P_D(Tc=25)	27	W
Operating and Storage Temperature Range	T_J,T_{STG}	-55 to 150	
Junction-to-Case n	$R_{\theta JC}$		

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Continuous Diode Forward Current	I_S				11	A
Total Gate Charge	Q_g	V_{DS}=480V I_D=5.5A V_{GS}=10V	-	19.2		nC

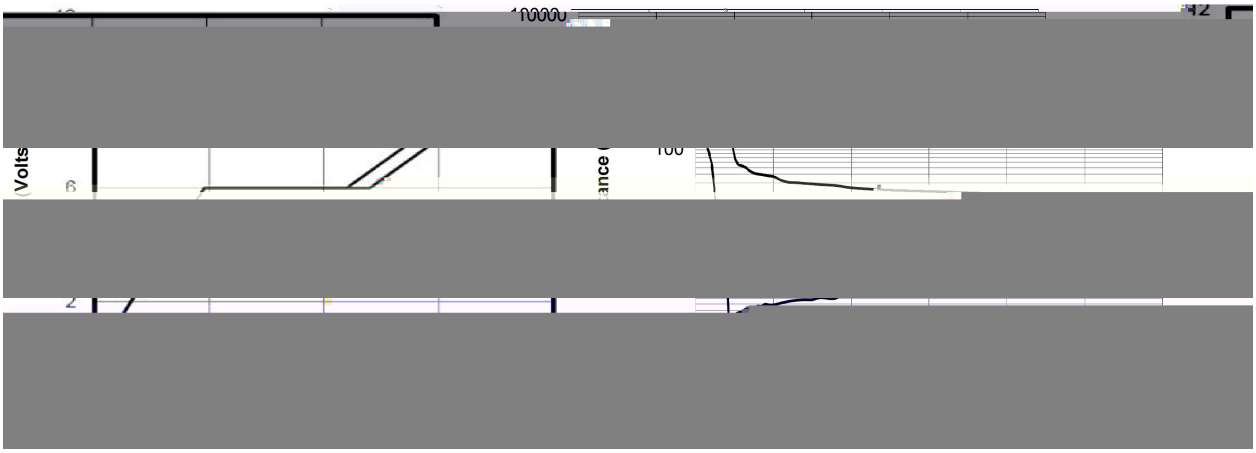
/ Electrical Characteristic Curve

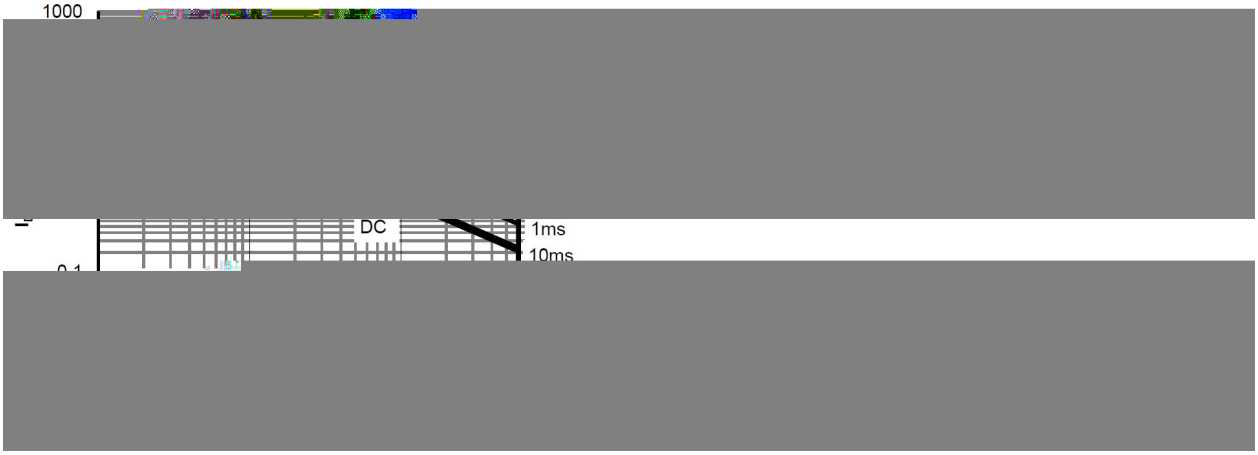






/ Electrical Characteristic Curve







/ Package Dimensions



BRF65R380C